	Application No.	Applicant(s)
	10/623,967	LU ET AL.
Notice of Allowability	Examiner	Art Unit
	Felisa C. Hiteshew	1722
The MAILING DATE of this communication app All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT F of the Office or upon petition by the applicant. See 37 CFR 1.31	S (OR REMAINS) CLOSED in t 5) or other appropriate commur RIGHTS. This application is su	his application. If not included ication will be mailed in due course. <b>THIS</b>
1. $\boxtimes$ This communication is responsive to <u>the amendment filed</u>	d on April 21, 2005.	
2. A The allowed claim(s) is/are <u>1-23</u> .		
3. 🖾 The drawings filed on are accepted by the Examine	er.	
4. Acknowledgment is made of a claim for foreign priority of a) All b) Some* c) None of the:  1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have 1. Copies of the certified copies of the priority documents have 1. Certified copies of the certified copies of the priority documents have 1. Certified copies of the certified copies of the priority documents have 1. Certified copies not received:  Applicant has THREE MONTHS FROM THE "MAILING DATE noted below. Failure to timely comply will result in ABANDONI THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	ve been received. ve been received in Application ocuments have been received " of this communication to file a	No in this national stage application from the
5. A SUBSTITUTE OATH OR DECLARATION must be subminFORMAL PATENT APPLICATION (PTO-152) which give		
6. CORRECTED DRAWINGS ( as "replacement sheets") mu  (a) including changes required by the Notice of Draftspel  1) hereto or 2) to Paper No./Mail Date  (b) including changes required by the attached Examinet Paper No./Mail Date  Identifying indicia such as the application number (see 37 CFR each sheet. Replacement sheet(s) should be labeled as such in	rson's Patent Drawing Review  r's Amendment / Comment or in  1.84(c)) should be written on the	n the Office action of drawings in the front (not the back) of
7. DEPOSIT OF and/or INFORMATION about the department attached Examiner's comment regarding REQUIREMENT		
Attachment(s)  1. ☐ Notice of References Cited (PTO-892)  2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)  3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB, Paper No./Mail Date  4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material	6. Interview Sur Paper No./M /08), 7. Examiner's A	rmal Patent Application (PTO-152) nmary (PTO-413), lail Date mendment/Comment tatement of Reasons for Allowance  FELISA HITESHEW PRIMARY EXAMINER  AUL (TOX

U.S. Patent and Trademark Office PTOL-37 (Rev. 1-04)

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## Allowable Subject Matter

1. Claims 1-23 are allowed.

2. The following is an examiner's statement of reasons for allowance: The most relevant prior art of reference was that which was submitted by the applicants. However, they do not teach nor fairly suggest singularly or in any combination thereof a method for use with a crystal growing apparatus for optimizing a cooling rate of a monocrystalline ingot grown according to a Czochralski process, said crystal growing apparatus having a heated crucible containing a semiconductor melt from which the ingot is grown, said ingot being grown on a seed crystal pulled from the melt, said crystal growing apparatus having a receiving chamber into which the ingot is pulled, said ingot being pulled along a generally longitudinal path toward the receiving chamber said method comprising: determining a first temperature of the ingot when the ingot is at a first position along the path; determining a second temperature of the ingot when the ingot is at a second position along the path, said first and second positions being separated by a distance D along the path; determining a cooling rate of the ingot as a function of a difference between the first temperature and the second temperature relative to an amount of time for pulling the ingot the distance D; generating a signal representative of an error between a target cooling rate of the ingot and the determined cooling rate of the ingot; and adjusting one or more post-growth processing parameters as a function of the error signal thereby to control the cooling rate of the ingot.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably Art Unit: 1722

accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Felisa Hiteshew whose telephone number is (571) 272-1463. The examiner can normally be reached on Mondays through Thursdays from 4:30 AM to 3:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Benjamin Utech, can be reached on (571) 272-1137. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-1463.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system. see <a href="http://pair-direct.uspto.gov">http://pair-direct.uspto.gov</a>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866- 217-9197 (toll-free).

FELISA HITESHEW PRIMARY EXAMINER